## **LS E65B**

#### Power TOPLED® Lens

PowerTOPLED with lens, a powerful member of the TOPLED family. Thanks to their high luminous efficacy, the LEDs are ideal for rear light clusters and indicators on vehicles and for display panels for traffic control systems.







### **Applications**

- Interior Illumination (e.g. Ambient Map)
- Traffic Lights

Signalling

#### Features:

- Package: white PLCC-4 package, colorless clear resin
- Chip technology: InGaAIP
- Typ. Radiation: 60°
- − Color:  $λ_{dom}$  = 633 nm (• super red)
- Corrosion Robustness Class: 3B
- ESD: 2 kV acc. to ANSI/ESDA/JEDEC JS-001 (HBM, Class 2)



Ordering Information		
Туре	Luminous Intensity 1)  I <sub>F</sub> = 50 mA I <sub>v</sub>	Ordering Code
LS E65B-V1BB-1-1	710 2800 mcd	Q65110A2762



### LS E65B

Maximum Ratings			
Parameter	Symbol		Values
Operating Temperature	T <sub>op</sub>	min. max.	-40 °C 100 °C
Storage Temperature	$T_{stg}$	min. max.	-40 °C 100 °C
Junction Temperature	T <sub>j</sub>	max.	125 °C
Forward current T <sub>s</sub> = 25 °C	I <sub>F</sub>	max.	70 mA
Surge Current t $\leq$ 10 $\mu$ s; D = 0.005 ; T <sub>s</sub> = 25 °C	I <sub>FS</sub>	max.	100 mA
Reverse voltage <sup>2)</sup> T <sub>S</sub> = 25 °C	$V_R$	max.	12 V
ESD withstand voltage acc. to ANSI/ESDA/JEDEC JS-001 (HBM, Class 2)	$V_{ESD}$		2 kV



### LS E65B

Characteristics
$I_F$ = 50 mA; $T_S$ = 25 °C

Parameter	Symbol		Values
Peak Wavelength 3)	$\lambda_{peak}$	typ.	645 nm
Dominant Wavelength 3)	$\lambda_{dom}$	min.	627 nm
$I_F = 50 \text{ mA}$	dom	typ.	633 nm
		max.	639 nm
Spectral Bandwidth at 50% I <sub>rel,max</sub>	Δλ	typ.	15 nm
Viewing angle at 50 % $\rm I_{\rm V}$	2φ	typ.	60 °
Forward Voltage 4)	V <sub>F</sub>	min.	1.90 V
$I_F = 50 \text{ mA}$		typ.	2.20 V
		max.	2.50 V
Reverse current <sup>2)</sup>	I <sub>R</sub>	typ.	0.01 μΑ
V <sub>R</sub> = 12 V		max.	10 µA
Temperature Coefficient of Peak Wavelength -10°C ≤ T ≤ 100°C	$TC_{\lambda peak}$	typ.	0.15 nm / K
Temperature Coefficient of Dominant Wavelength -10°C ≤ T ≤ 100°C	$TC_{\lambda dom}$	typ.	0.05 nm / K
Temperature Coefficient of Forward Voltage -10°C ≤ T ≤ 100°C	$TC_{VF}$	typ.	-3.4 mV / K
Real thermal resistance junction/solderpoint 5)	R <sub>thJS real</sub>	typ.	110 K / W
	and real	max.	130 K / W



# **Brightness Groups**

Group	Luminous Intensity 1) I <sub>F</sub> = 50 mA	Luminous Intensity. 1) I <sub>F</sub> = 50 mA	Luminous Flux <sup>6)</sup> I <sub>F</sub> = 50 mA
	min.	max.	typ.
	l <sub>v</sub>	l <sub>v</sub>	$\Phi_{V}$
V1	710 mcd	900 mcd	1020 mlm
V2	900 mcd	1120 mcd	1280 mlm
AA	1120 mcd	1400 mcd	1590 mlm
AB	1400 mcd	1800 mcd	2020 mlm
ВА	1800 mcd	2240 mcd	2560 mlm
BB	2240 mcd	2800 mcd	3190 mlm

# **Forward Voltage Groups**

Group Forward Voltage 4) $I_F = 50 \text{ mA}$		Forward Voltage <sup>4)</sup> I <sub>F</sub> = 50 mA	
	min.	max.	
	$V_{F}$	$V_{F}$	
3	1.90 V	2.20 V	
4	2.20 V	2.50 V	



## **Group Name on Label**

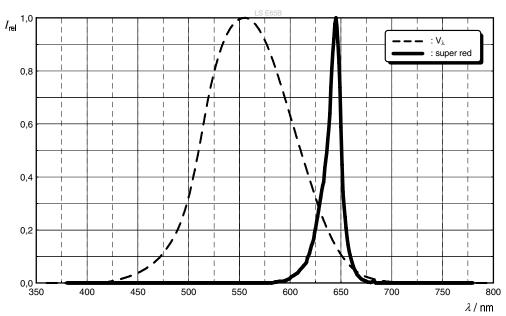
Example: AA-1-3

Brightness	Wavelength	Forward Voltage
AA	1	3



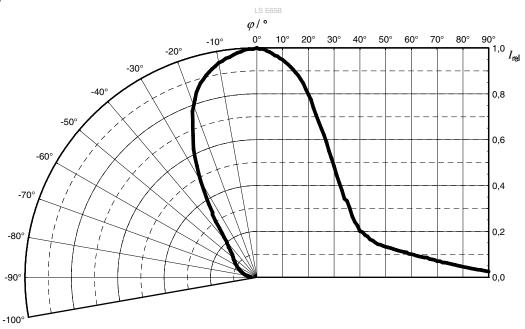
## Relative Spectral Emission 6)

$$I_{rel}$$
 = f ( $\lambda$ );  $I_F$  = 50 mA;  $T_S$  = 25 °C



#### Radiation Characteristics 6)

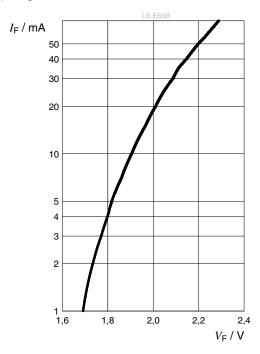
$$I_{rel} = f (\phi); T_S = 25 \, ^{\circ}C$$





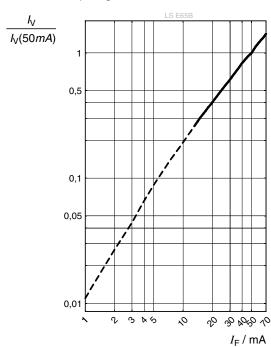
## Forward current 6), 7)

$$I_F = f(V_F); T_S = 25 \, ^{\circ}C$$



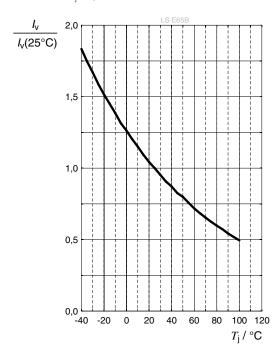
## Relative Luminous Intensity 6), 7)

$$I_v/I_v$$
(50 mA) =  $f(I_F)$ ;  $T_S$  = 25 °C



## Relative Luminous Intensity 6)

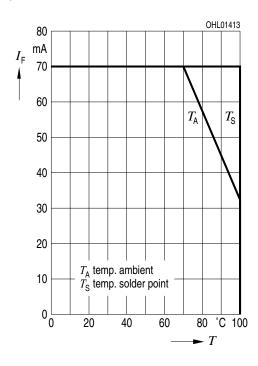
 $I_{v}/I_{v}(25 \text{ °C}) = f(T_{j}); I_{F} = 50 \text{ mA}$ 





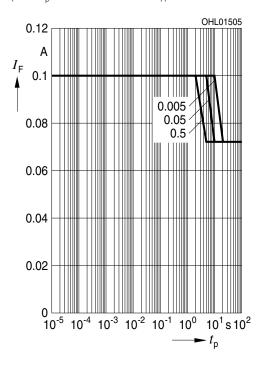
#### Max. Permissible Forward Current

 $I_F = f(T)$ 



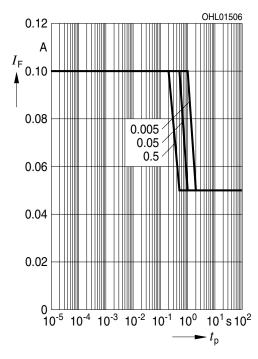
### **Permissible Pulse Handling Capability**

 $I_F = f(t_p)$ ; D: Duty cycle;  $T_A = 25 \, ^{\circ}C$ 

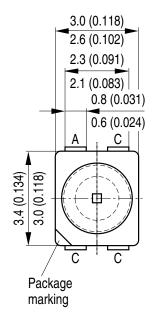


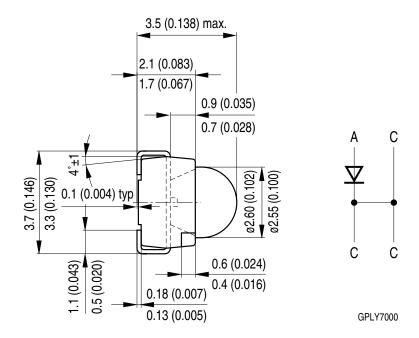
### **Permissible Pulse Handling Capability**

 $I_{_{\rm F}}$  = f(t $_{_{\rm p}}$ ); D: Duty cycle;  $T_{_{\rm A}}$  = 85 °C



### **Dimensional Drawing** 8)





Approximate Weight: 38.0 mg

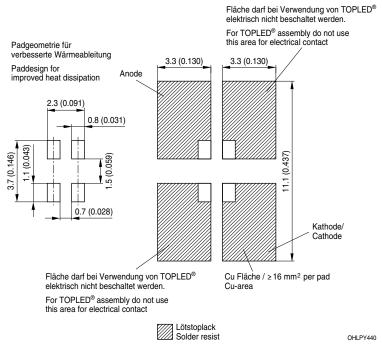
Package marking: Cathode

Corrosion test: Class: 3B

Test condition:  $40^{\circ}$ C / 90 % RH / 15 ppm H<sub>2</sub>S / 14 days (stricter then IEC

60068-2-43)

### Recommended Solder Pad 8)

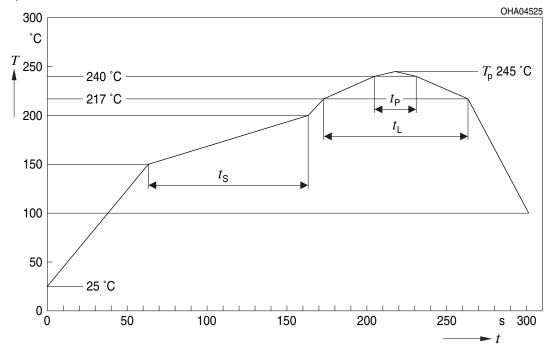


For superior solder joint connectivity results we recommend soldering under standard nitrogen atmosphere. Package not suitable for ultra sonic cleaning.



### **Reflow Soldering Profile**

Product complies to MSL Level 2 acc. to JEDEC J-STD-020E

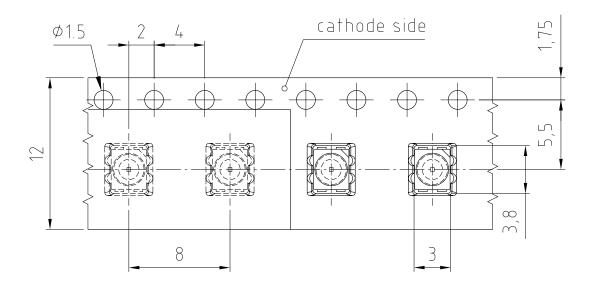


Profile Feature	e Feature Symbol Pb-Free (SnAgCu) Assembly			Unit	
		Minimum	Recommendation	Maximum	
Ramp-up rate to preheat*) 25 °C to 150 °C			2	3	K/s
Time t <sub>s</sub> T <sub>Smin</sub> to T <sub>Smax</sub>	t <sub>s</sub>	60	100	120	S
Ramp-up rate to peak*) $T_{\rm Smax}$ to $T_{\rm P}$			2	3	K/s
Liquidus temperature	$T_L$		217		°C
Time above liquidus temperature	$t_{\scriptscriptstyle \perp}$		80	100	S
Peak temperature	T <sub>P</sub>		245	250	°C
Time within 5 °C of the specified peak temperature T <sub>p</sub> - 5 K	t <sub>P</sub>	10	20	30	S
Ramp-down rate* T <sub>P</sub> to 100 °C			3	4	K/s
Time 25 °C to T <sub>P</sub>				480	S

All temperatures refer to the center of the package, measured on the top of the component  $^{\star}$  slope calculation DT/Dt: Dt max. 5 s; fulfillment for the whole T-range



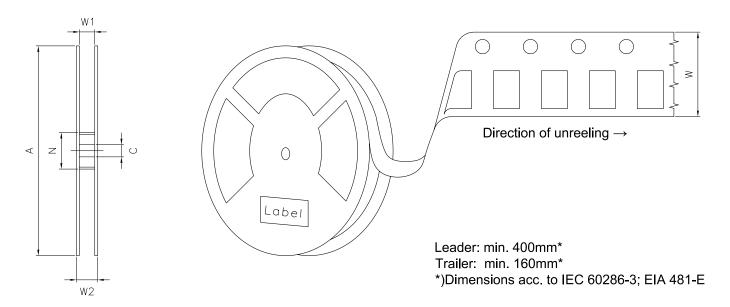
# Taping 8)



C63062-A3533-B01-02



## Tape and Reel 9)



## Reel dimensions [mm]

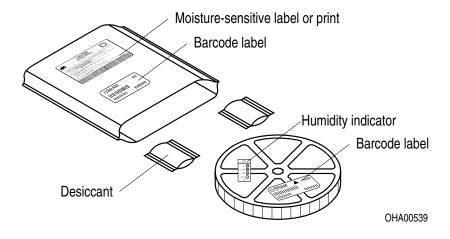
A	W	$N_{\min}$	W <sub>1</sub>	$W_{2 \text{ max}}$	Pieces per PU
330 mm	12 + 0.3 / - 0.1	60	12.4 + 2	18.4	2000



# **Barcode-Product-Label (BPL)**



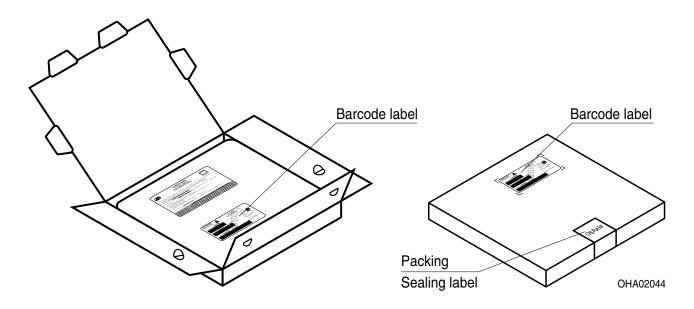
## **Dry Packing Process and Materials 8)**



Moisture-sensitive product is packed in a dry bag containing desiccant and a humidity card according JEDEC-STD-033.



# Transportation Packing and Materials 8)



## Dimensions of transportation box in mm

Width	Length	Height
349 ± 5 mm	349 ± 5 mm	33 ± 5 mm



# **Type Designation System**

Wavelength (λ <sub>dom</sub> typ.) A: 617 nm S: 633 nm T: 528 nm Y: 587 nm O: 606 nm	amber super red true green yellow orange	Color coordinates CIE 1931/Emission W: white UW: ultra white CW: warm white CB: color on dema CR: crystal pink	color:	
<b>CP/P:</b> 560 nm <b>R:</b> 625 nm <b>B:</b> 470 nm	pure green red blue	Package E: Pov	Type werTOPLED	
L: Light emitting diode				
L A		E 6	7	6
	•	sion stability		
Encap 7: S: 3: 5:	Colorless clear or volume (resin encapsulations Silicone (with or with lens 30° 70° lens 40° 80°	white volume conversion)	ion	
	(e.g. 6 <b>F:</b> Thinfil <b>G:</b> ThinG	2000 2000    ost ThinGaN/ Thinfiln	n	



#### **Notes**

The evaluation of eye safety occurs according to the standard IEC 62471:2006 (photo biological safety of lamps and lamp systems). Within the risk grouping system of this IEC standard, the device specified in this data sheet falls into the class **exempt group (exposure time 10000 s)**. Under real circumstances (for exposure time, conditions of the eye pupils, observation distance), it is assumed that no endangerment to the eye exists from these devices. As a matter of principle, however, it should be mentioned that intense light sources have a high secondary exposure potential due to their blinding effect. When looking at bright light sources (e.g. headlights), temporary reduction in visual acuity and afterimages can occur, leading to irritation, annoyance, visual impairment, and even accidents, depending on the situation.

Subcomponents of this device contain, in addition to other substances, metal filled materials including silver. Metal filled materials can be affected by environments that contain traces of aggressive substances. Therefore, we recommend that customers minimize device exposure to aggressive substances during storage, production, and use. Devices that showed visible discoloration when tested using the described tests above did show no performance deviations within failure limits during the stated test duration. Respective failure limits are described in the IEC60810.

For further application related informations please visit www.osram-os.com/appnotes



#### **Disclaimer**

#### Disclaimer

Language english will prevail in case of any discrepancies or deviations between the two language wordings.

#### Attention please!

The information describes the type of component and shall not be considered as assured characteristics. Terms of delivery and rights to change design reserved. Due to technical requirements components may contain dangerous substances.

For information on the types in question please contact our Sales Organization.

If printed or downloaded, please find the latest version on the OSRAM OS webside.

#### **Packing**

Please use the recycling operators known to you. We can also help you – get in touch with your nearest

By agreement we will take packing material back, if it is sorted. You must bear the costs of transport. For packing material that is returned to us unsorted or which we are not obliged to accept, we shall have to invoice you for any costs incurred.

#### Product safety devices/applications or medical devices/applications

OSRAM OS components are not developed, constructed or tested for the application as safety relevant component or for the application in medical devices.

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#### Glossary

- Brightness: Brightness values are measured during a current pulse of typically 25 ms, with an internal reproducibility of ±8 % and an expanded uncertainty of ±11 % (acc. to GUM with a coverage factor of
- Reverse Operation: Reverse Operation of 10 hours is permissible in total. Continuous reverse operation is not allowed.
- 3) Wavelength: The wavelength is measured at a current pulse of typically 25 ms, with an internal reproducibility of ±0.5 nm and an expanded uncertainty of ±1 nm (acc. to GUM with a coverage factor of k = 3).
- Forward Voltage: The forward voltage is measured during a current pulse of typically 8 ms, with an internal reproducibility of ±0.05 V and an expanded uncertainty of ±0.1 V (acc. to GUM with a coverage factor of k = 3).
- 5) **Thermal Resistance**: Rth max is based on statistic values (6σ).
- Typical Values: Due to the special conditions of the manufacturing processes of semiconductor devices, the typical data or calculated correlations of technical parameters can only reflect statistical figures. These do not necessarily correspond to the actual parameters of each single product, which could differ from the typical data and calculated correlations or the typical characteristic line. If requested, e.g. because of technical improvements, these typ. data will be changed without any further notice.
- Characteristic curve: In the range where the line of the graph is broken, you must expect higher differences between single devices within one packing unit.
- Tolerance of Measure: Unless otherwise noted in drawing, tolerances are specified with ±0.1 and dimensions are specified in mm.
- Tape and Reel: All dimensions and tolerances are specified acc. IEC 60286-3 and specified in mm.



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